



STU/D2030PLS

SamHop Microelectronics Corp.

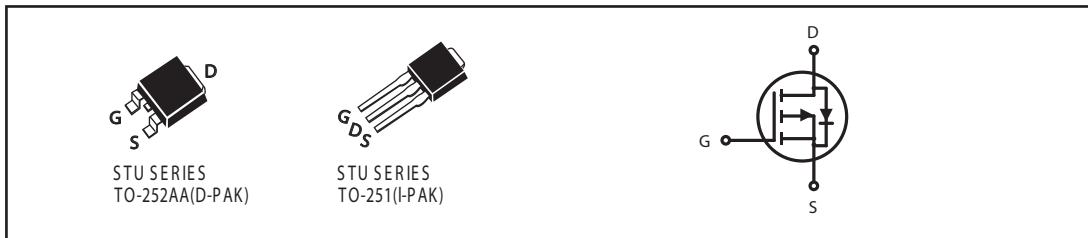
Aug 20 2005

P-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
V _{DSS}	I _D	R _{DSON} (mΩ) Max
-30V	-20A	32 @ V _{GS} = -10V
		55 @ V _{GS} = -4.5V

FEATURES

- Super high dense cell design for low R_{DSON}.
- Rugged and reliable.
- TO-252 and TO-251 Package.



ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-30	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous @ T _c =25°C -Pulsed ^a	I _D	-20	A
	I _{DM}	-60	A
Drain-Source Diode Forward Current	I _S	-20	A
Maximum Power Dissipation @ T _c =25°C	P _D	50	W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 to 175	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Case	R _{θJC}	3	°C/W
Thermal Resistance, Junction-to-Ambient	R _{θJA}	50	°C/W

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ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ ^c	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$	-25			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=-20\text{V}, V_{\text{GS}}=0\text{V}$		-1		μA
Gate-Body Leakage	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$		± 100		nA
ON CHARACTERISTICS ^a						
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$	-1	-1.7	-3	V
Drain-Source On-State Resistance	$R_{\text{DS(ON)}}$	$V_{\text{GS}}=-10\text{V}, I_{\text{D}}=-20\text{A}$		27	32	m ohm
		$V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-10\text{A}$		41	55	m ohm
On-State Drain Current	$I_{\text{D(ON)}}$	$V_{\text{DS}}=-10\text{V}, V_{\text{GS}}=-10\text{V}$	-30			A
Forward Transconductance	g_{FS}	$V_{\text{DS}}=-10\text{V}, I_{\text{D}}=-10\text{A}$		14		S
DYNAMIC CHARACTERISTICS ^b						
Input Capacitance	C_{ISS}	$V_{\text{DS}}=-15\text{V}, V_{\text{GS}}=0\text{V}$ $f=1.0\text{MHz}$		950		pF
Output Capacitance	C_{OSS}			250		pF
Reverse Transfer Capacitance	C_{RSS}			170		pF
Gate resistance	R_g	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=0\text{V}, f=1.0\text{MHz}$		2.6		ohm
SWITCHING CHARACTERISTICS ^b						
Turn-On Delay Time	$t_{\text{D(ON)}}$	$V_{\text{DD}}=-15\text{V}$ $I_{\text{D}}=-1\text{A}$ $V_{\text{GS}}=-10\text{V}$ $R_{\text{GEN}}=6\text{ ohm}$		10		ns
Rise Time	t_r			22		ns
Turn-Off Delay Time	$t_{\text{D(OFF)}}$			68.8		ns
Fall Time	t_f			38.5		ns
Total Gate Charge (10V)	Q_g	$V_{\text{DS}}=-15\text{V}, I_{\text{D}}=-20\text{A}$ $V_{\text{GS}}=-10\text{V}$		18.5		nC
Total Gate Charge (4.5V)				9.6		nC
Gate-Source Charge	Q_{gs}			1.6		nC
Gate-Drain Charge	Q_{gd}			5.8		nC

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ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
DRAIN-SOURCE DIODE CHARACTERISTICS ^a						
Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_s = -10A$		-0.9	-1.3	V

Notes

- a.Pulse Test:Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
- b.Guaranteed by design, not subject to production testing.

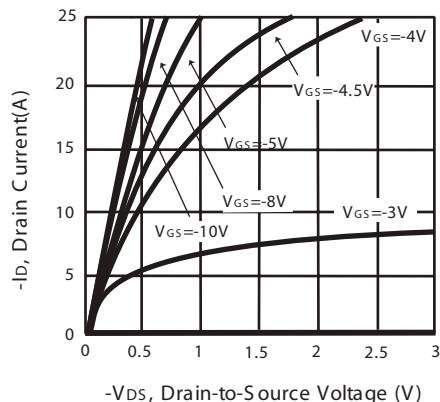


Figure 1. Output Characteristics

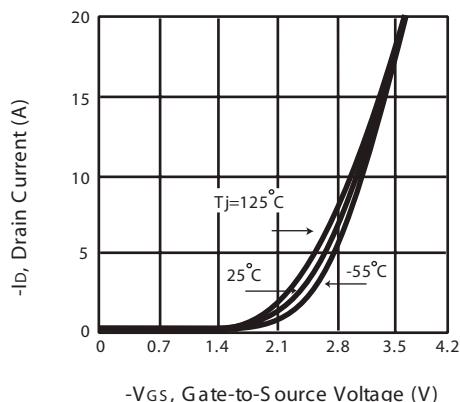


Figure 2. Transfer Characteristics

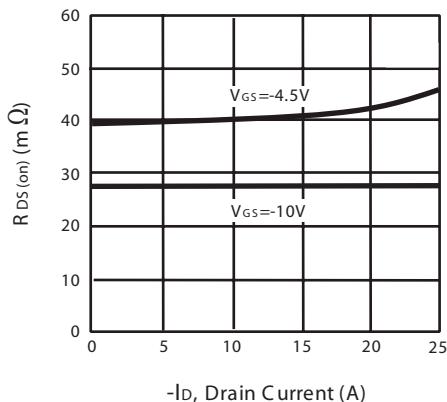


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

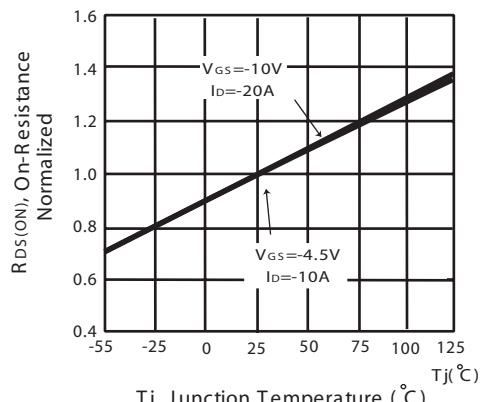
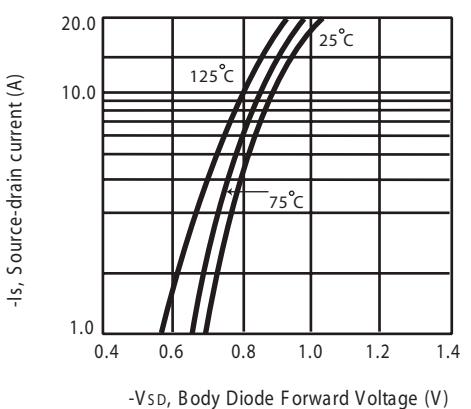
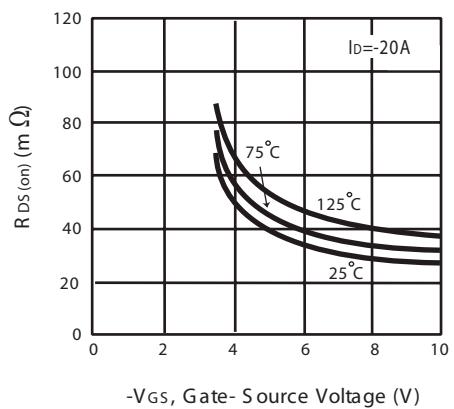
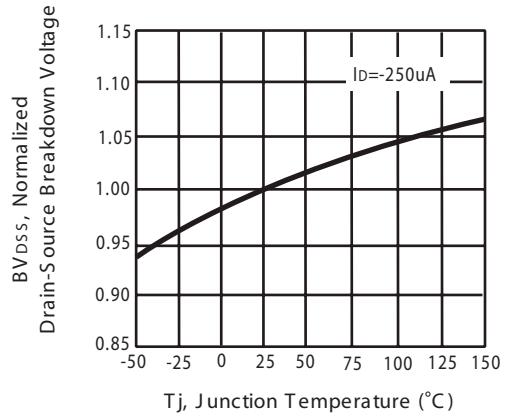
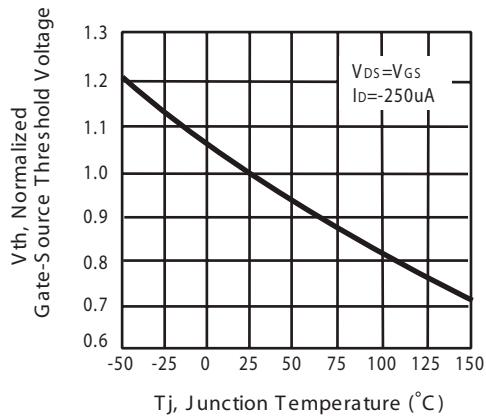


Figure 4. On-Resistance Variation with Drain Current and Temperature

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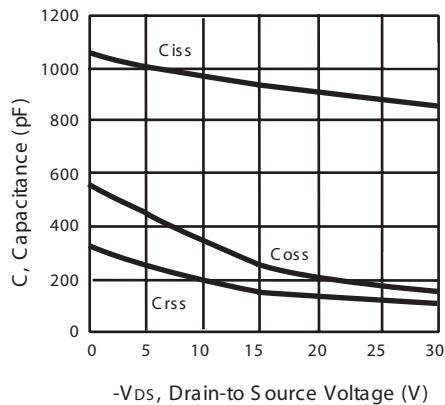


Figure 9. Capacitance

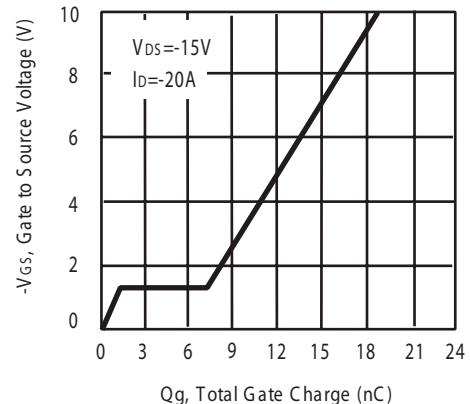


Figure 10. Gate Charge

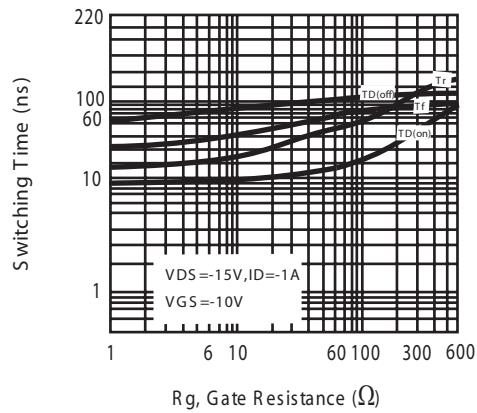


Figure 11. switching characteristics

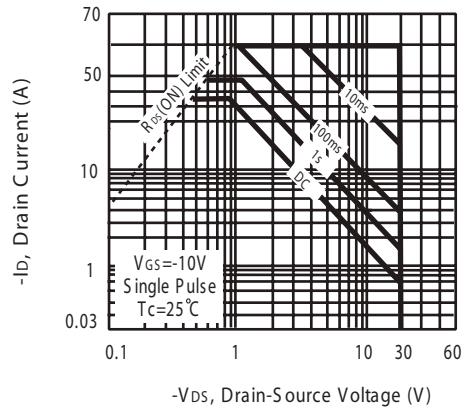


Figure 10. Maximum Safe Operating Area

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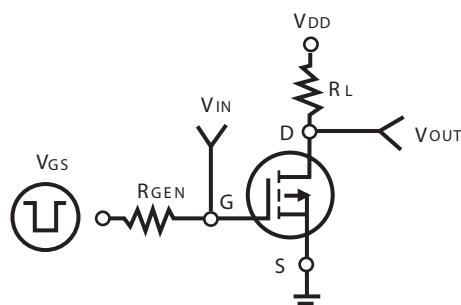


Figure 11. S switching Test Circuit

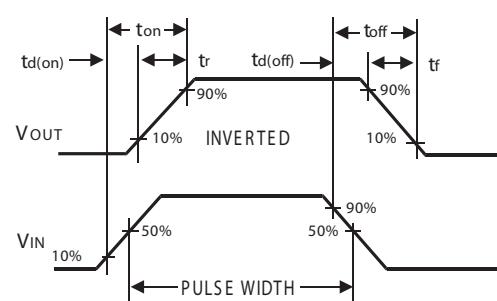


Figure 12. S switching Waveforms

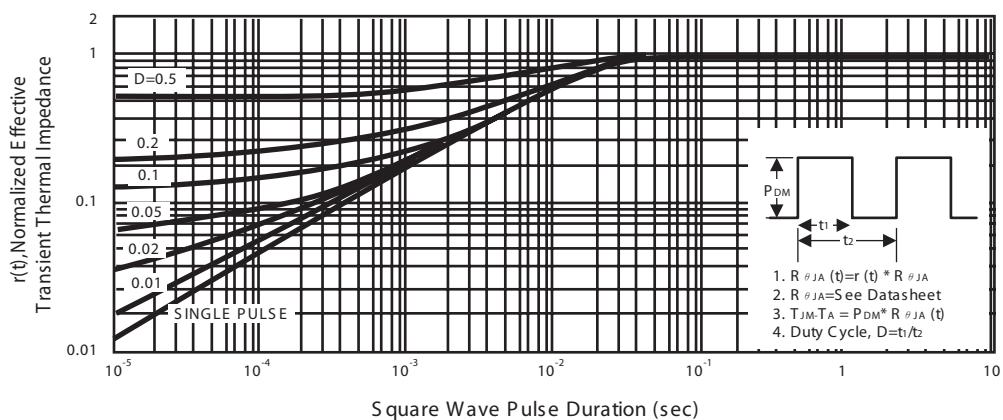
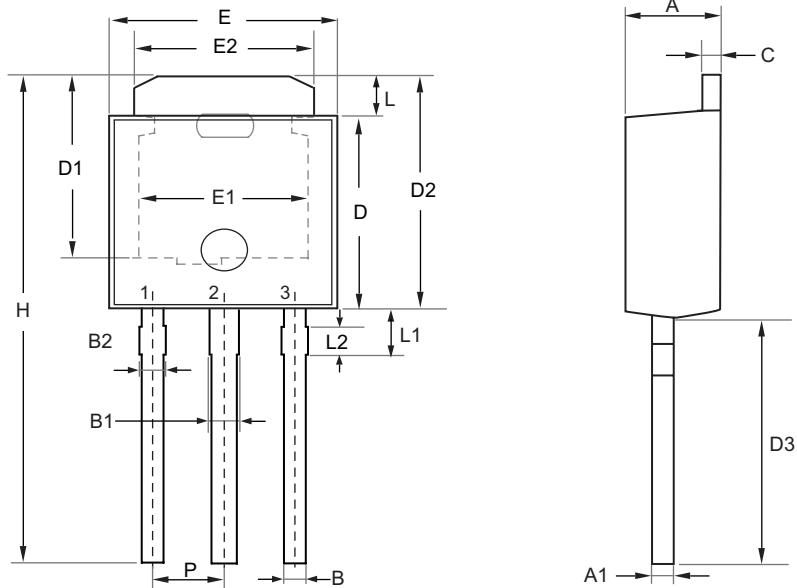


Figure 13. Normalized Thermal Transient Impedance Curve

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PACKAGE OUTLINE DIMENSIONS

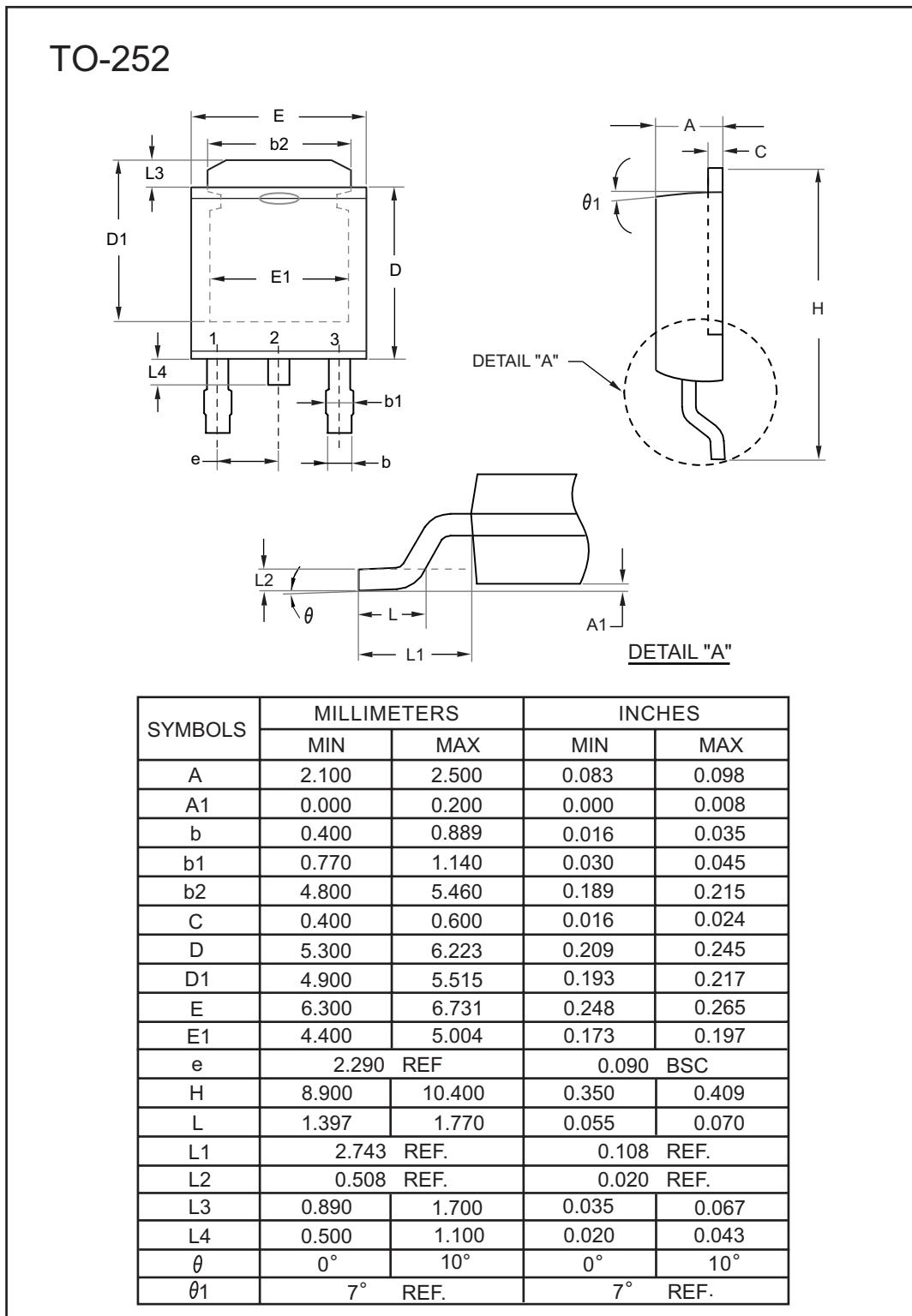
TO-251



SYMBOL	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.100	2.500	0.083	0.098
A1	0.350	0.650	0.014	0.026
B	0.400	0.800	0.016	0.031
B1	0.650	1.050	0.026	0.041
B2	0.500	0.900	0.020	0.035
C	0.400	0.600	0.016	0.024
D	5.300	5.700	0.209	0.224
D1	4.900	5.300	0.193	0.209
D2	6.700	7.300	0.264	0.287
D3	7.000	8.000	0.276	0.315
H	13.700	15.300	0.539	0.602
E	6.300	6.700	0.248	0.264
E1	4.600	4.900	0.181	0.193
E2	4.800	5.200	0.189	0.205
L	1.300	1.700	0.051	0.067
L1	1.400	1.800	0.055	0.071
L2	0.500	0.900	0.020	0.035
P	2.300 BSC		0.091 BSC	

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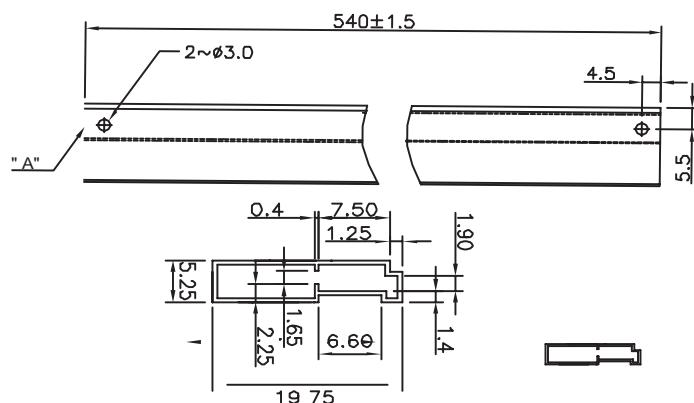
PACKAGE OUTLINE DIMENSIONS



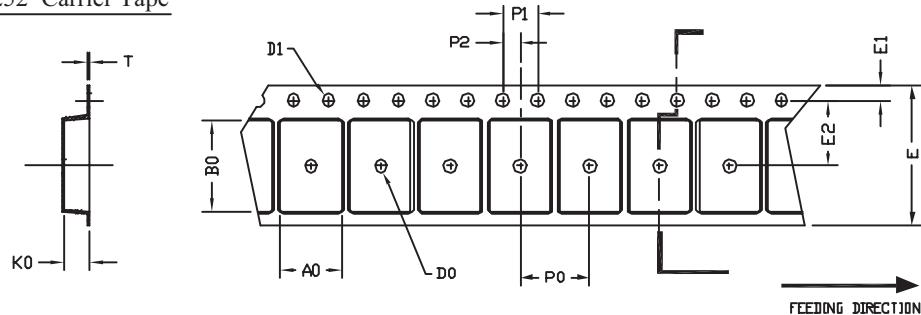
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TO251 Tube/TO-252 Tape and Reel Data

TO-251 Tube



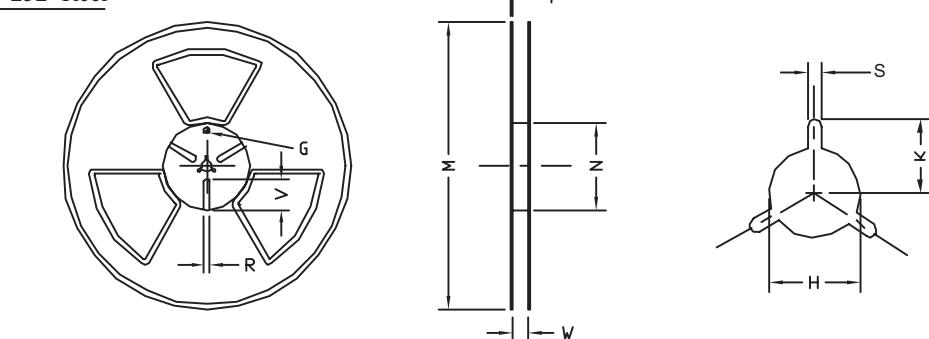
TO-252 Carrier Tape



UNIT:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
TO-252 (16 mm)	6.80 ±0.1	10.3 ±0.1	2.50 ±0.1	ϕ 2	ϕ 1.5 + 0.1 - 0	16.0 0.3±	1.75 0.1±	7.5 ±0.15	8.0 ±0.1	4.0 ±0.1	2.0 ±0.15	0.3 ±0.05

TO-252 Reel



UNIT:mm

TAPE SIZE	REEL SIZE	M	N	W	T	H	K	S	G	R	V
16 mm	ϕ 330	ϕ 330 ± 0.5	ϕ 97 ± 1.0	17.0 + 1.5 - 0	2.2	ϕ 13.0 + 0.5 - 0.2	10.6	2.0 ± 0.5	---	---	---